Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	-20	V
Collector-Emitter Voltage	V_{CEO}	-20	V
Emitter-Base Voltage	V_{EBO}	-7	V
Base Current	I_B	-500	mA
Continuous Collector Current	I_C	-2.5	A
Peak Pulse Collector Current	I_{CM}	-6	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

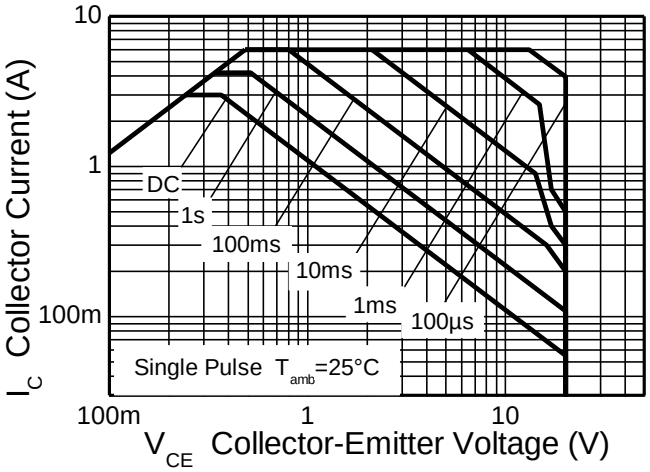
Characteristic		Symbol	Value	Unit
Power Dissipation Linear Derating Factor	(Note 5)	P_D	1.1 8.8	W mW/°C
	(Note 6)		1.7 13.6	
Thermal Resistance, Junction to Ambient	(Note 5)	$R_{\theta JA}$	113	°C/W
	(Note 6)		73	
Thermal Resistance, Junction to Leads	(Note 7)	$R_{\theta JL}$	30.01	°C/W
Operating and Storage Temperature Range		T_J, T_{STG}	-55 to +150	°C

ESD Ratings (Note 8)

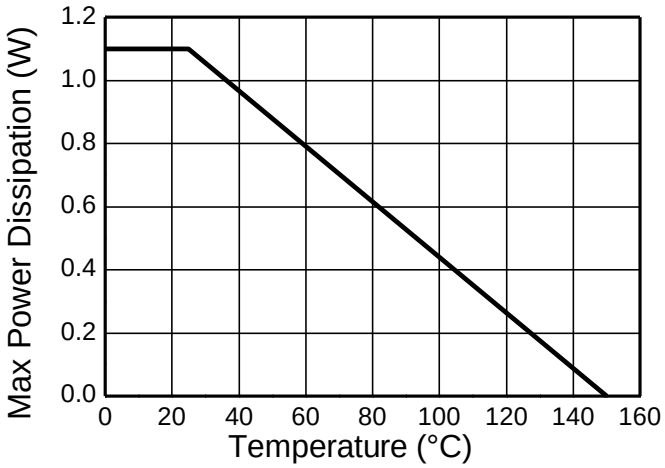
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

Notes:
5. For a device mounted with collector leads on 25mm x 25mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
6. Same as Note 5, except the device is measured at $t \leq 5$secs.
7. Thermal resistance from junction to solder-point (at the end of the collector leads).
8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

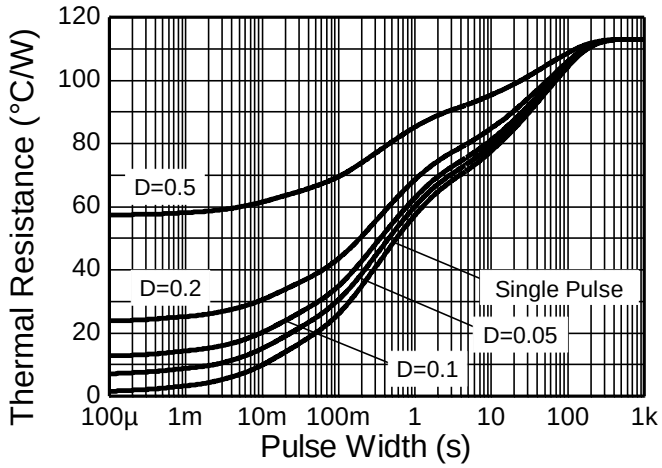
Thermal Characteristics and Derating Information



Safe Operating Area



Derating Curve



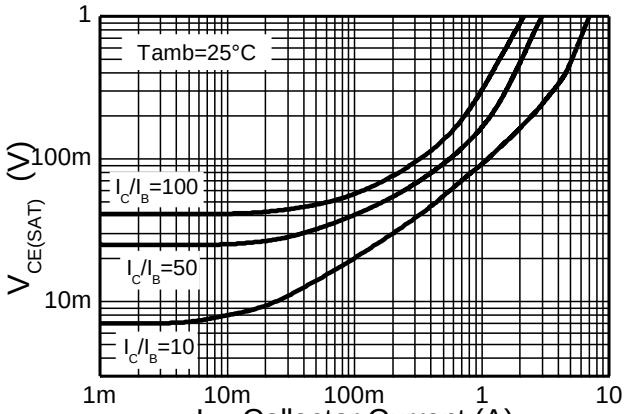
Transient Thermal Impedance

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

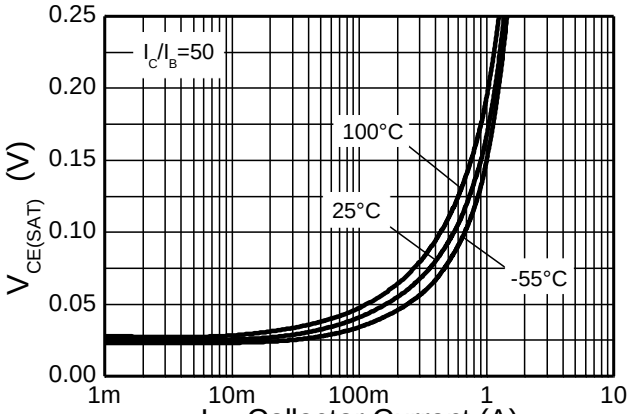
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Collector-Base Breakdown Voltage	BV_{CBO}	-20	-65	—	V	I_C = -100µA
Collector-Emitter Breakdown Voltage (Note 9)	BV_{CEO}	-20	-53	—	V	I_C = -10mA
Emitter-Base Breakdown Voltage	BV_{EBO}	-7	-8.8	—	V	I_E = -100µA
Collector-Base Cutoff Current	I_{CBO}	—	<1	-100	nA	V_{CB} = -15V
Emitter Cutoff Current	I_{EBO}	—	<1	-100	nA	V_{EB} = -5V
Collector-Emitter Cutoff Current	I_{CES}	—	<1	-100	nA	V_{CES} = -15V
ON CHARACTERISTICS (Note 9)						
DC Current Gain	h_{FE}	300	475	—	—	I_C = -10mA, V_{CE} = -2V
		300	450	—	—	I_C = -0.1A, V_{CE} = -2V
		150	230	—	—	I_C = -2A, V_{CE} = -2V
		15	30	—	—	I_C = -6A, V_{CE} = -2V
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	—	-19	-30	mV	I_C = -0.1A, I_B = -10mA
		—	-170	-220		I_C = -1A, I_B = -20mA
		—	-190	-250		I_C = -1.5A, I_B = -50mA
		—	-240	-350		I_C = -2.5A, I_B = -150mA
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	—	-0.97	-1.05	V	I_C = -2.5A, I_B = -150mA
Base-Emitter Turn-On Voltage	$V_{BE(on)}$	—	-0.85	-0.95	V	I_C = -2.5A, V_{CE} = -2V
SMALL SIGNAL CHARACTERISTICS						
Current Gain-Bandwidth Product	f_T	150	180	—	MHz	V_{CE} = -10V, I_C = -50mA, f = 100MHz
Output Capacitance	C_{obo}	—	21	30	pF	V_{CB} = -10V, f = 1MHz
Turn-On Time	$t_{(on)}$	—	40	—	ns	V_{CC} = -10V, I_C = -1A
Turn-Off Time	$t_{(off)}$	—	670	—	ns	I_{B1} = -I_{B2} = -20mA

Note: 9. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤ 2%.

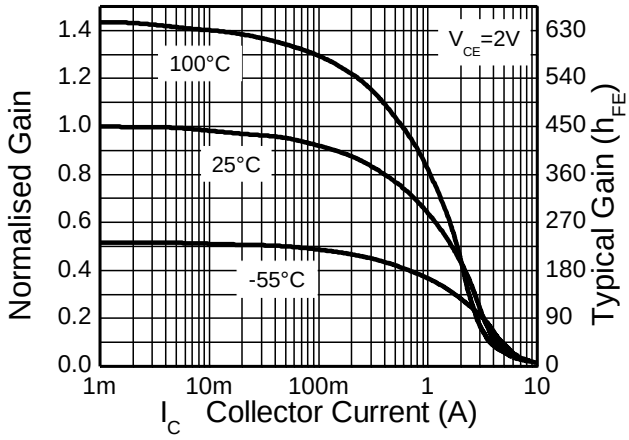
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)



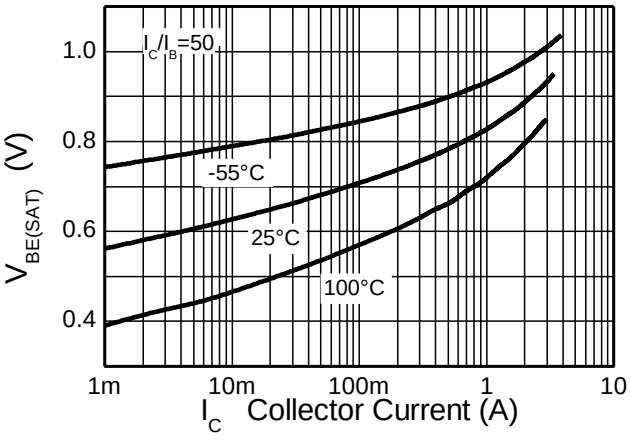
$V_{CE(SAT)}$ v I_C



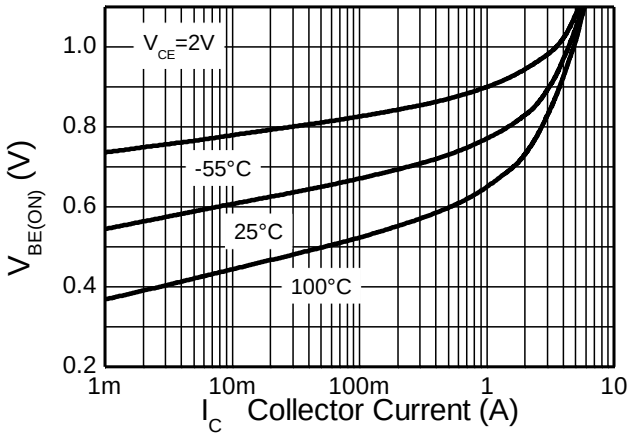
$V_{CE(SAT)}$ v I_C



h_{FE} v I_C



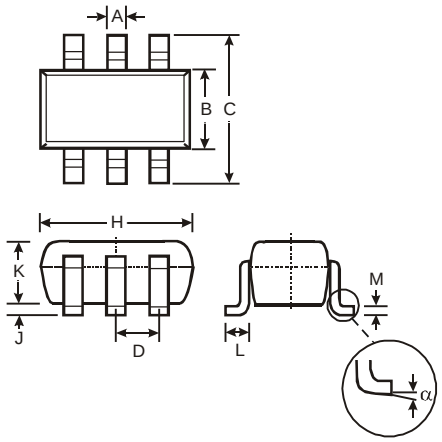
$V_{BE(SAT)}$ v I_C



$V_{BE(ON)}$ v I_C

Package Outline Dimensions

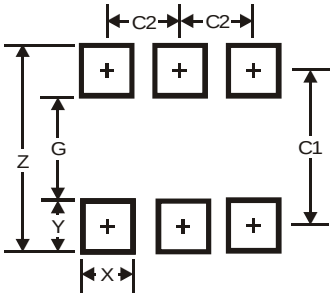
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SOT26			
Dim	**Min**	**Max**	**Typ**
A	0.35	0.50	0.38
B	1.50	1.70	1.60
C	2.70	3.00	2.80
D	—	—	0.95
H	2.90	3.10	3.00
J	0.013	0.10	0.05
K	1.00	1.30	1.10
L	0.35	0.55	0.40
M	0.10	0.20	0.15
α	0°	8°	—
All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	3.20
G	1.60
X	0.55
Y	0.80
C1	2.40
C2	0.95

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